2STR2215

Low voltage fast-switching PNP power transistor

Features

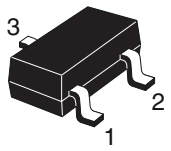
- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed
- Miniature SOT-23 plastic package for surface mounting circuits

Applications

- LED
- Battery charger
- Motor and relay driver
- Voltage regulation

Description

The 2STR2215 is a PNP transistor manufactured using new “PB-HCD” (power bipolar high current density) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.
The complementary NPN is the 2STR1215.



SOT-23

Figure 1. Internal schematic diagram

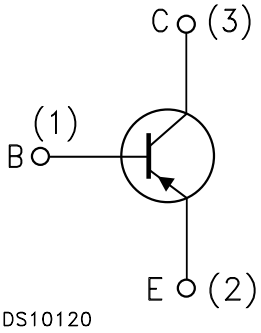


Table 1. Device summary

Order code	Marking	Package	Packaging
2STR2215	215	SOT-23	Tape and reel

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-base voltage (I_E = 0)	-15	V
V_{CEO}	Collector-emitter voltage (I_B = 0)	-15	V
V_{EBO}	Emitter-base voltage (I_C = 0)	-5	V
I_C	Collector current	-1.5	A
I_{CM}	Collector peak current (t_P < 5 ms)	-3	A
P_{tot}	Total dissipation at T_{amb} = 25 °C	0.5	W
T_{stg}	Storage temperature	-65 to 150	°C
T_J	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter		Value	Unit
$R_{thj\text{-}amb}$ (1)	Thermal resistance junction-amb	max	250	°C/W

1. Device mounted on PCB area of 1cm^2

2 Electrical characteristics

(T_{case} = 25 °C unless otherwise specified)

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector cut-off current (I_E =0)	V_{CB} = -15 V			-0.1	µA
I_{EBO}	Emitter cut-off current (I_C =0)	V_{EB} = -4 V			-0.1	µA
$V_{(BR)CBO}$	Collector-base breakdown voltage (I_E = 0)	I_C = -100 µA	-15			V
$V_{(BR)CEO}$ (1)	Collector-emitter breakdown voltage (I_B = 0)	I_C = -10 mA	-15			V
$V_{(BR)EBO}$	Emitter-base breakdown voltage (I_C = 0)	I_E = -100 µA	-5			V
$V_{CE(sat)}$ (1)	Collector-emitter saturation voltage	I_C = -100 mA I_B = -1 mA I_C = -1 A I_B = -100 mA I_C = -2 A I_B = -200 mA		 -0.25 -0.40	-0.15 -0.50 -0.85	V V V
$V_{BE(sat)}$ (1)	Base-emitter saturation voltage	I_C = -1 A I_B = -100 mA		-0.90	-1.25	V
h_{FE} (1)	DC current gain	I_C = -50 mA V_{CE} = -2 V I_C = -500 mA V_{CE} = -2 V I_C = -1 A V_{CE} = -2 V I_C = -2 A V_{CE} = -2 V	200 200 130 80	280	560	
C_{CBO}	Collector-base capacitance (I_E = 0)	V_{CB} = -10 V f = 1 MHz		20		pF
t_{on} t_{off}	Resistive load Turn-on time Turn-off time	I_C = -1.5 A V_{CC} = -10 V I_{B1} = -I_{B2} = -150 mA		60 220		ns ns

1. Pulsed duration = 300 µs, duty cycle ≤1.5%

2.1 Electrical characteristics (curves)

Figure 2. DC current gain

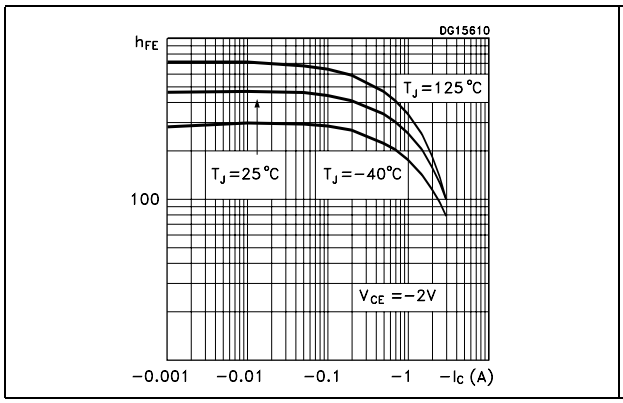


Figure 3. Collector-emitter saturation voltage

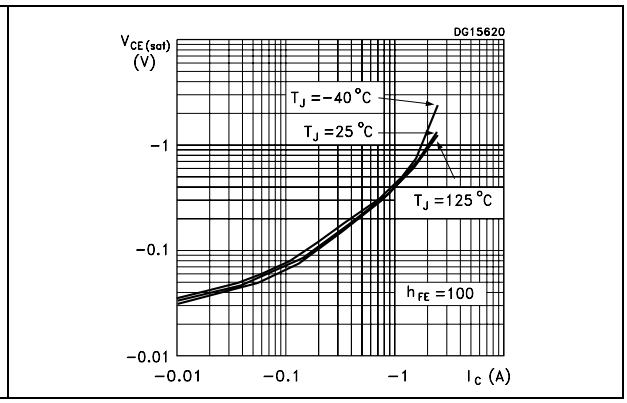


Figure 4. Base-emitter saturation voltage

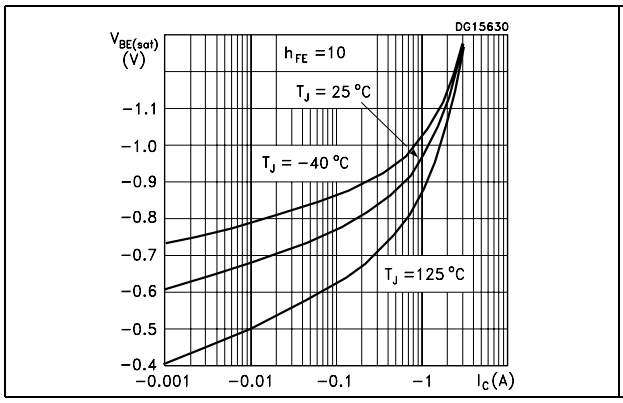


Figure 5. Resistive load switching time

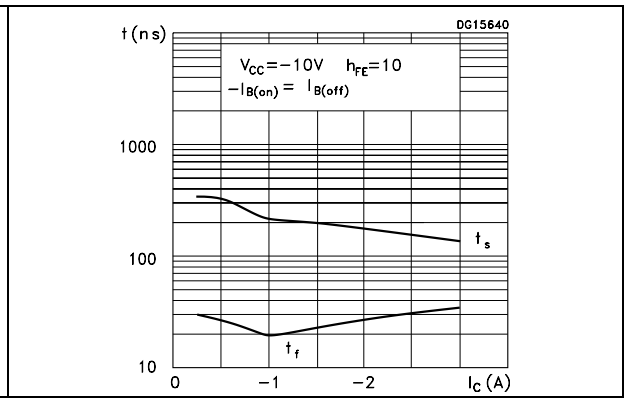


Figure 6. Resistive load switching time

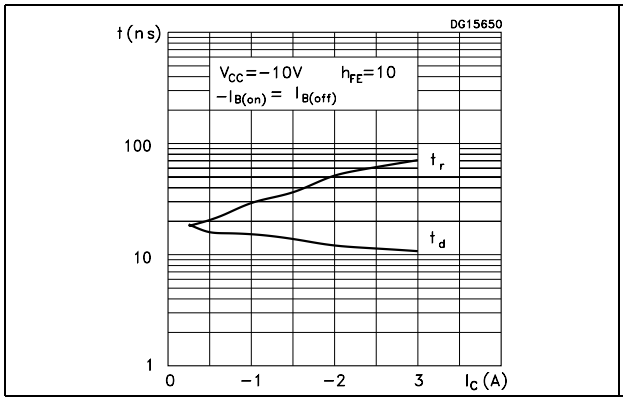
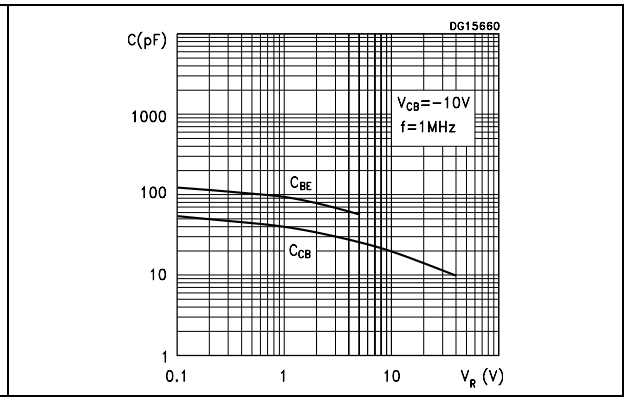
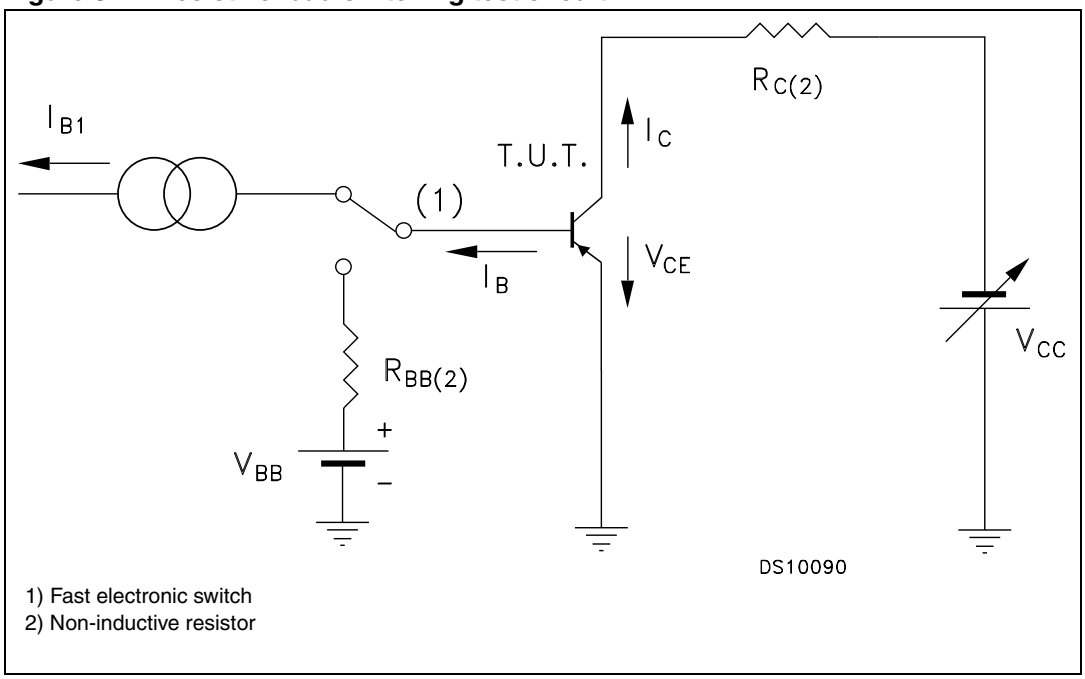


Figure 7. Capacitance



2.2 Test circuit

Figure 8. Resistive load switching test circuit



1) Fast electronic switch
2) Non-inductive resistor

3 Package mechanical data

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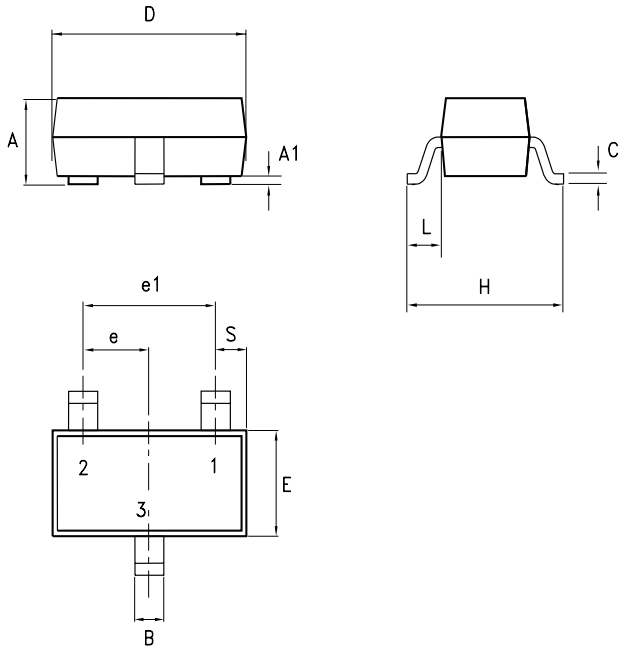
SOT-23 mechanical data

DIM.	mm.		
	min.	typ	max.
A	0.89		1.4
A1	0		0.1
B	0.3		0.51
C	0.085		0.18
D	2.75		3.04
e	0.85		1.05
e1	1.7		2.1
E	1.2		1.6
H	2.1		2.75
L		0.6	
S	0.35		0.65



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4 Revision history

Table 5. Document revision history

Date	Revision	Changes
09-Feb-2006	1	Initial release.
20-Jul-2006	2	New template.
08-Sep-2008	3	Updated the SOT-23 mechanical data.
08-Jan-2009	4	Updated *Figure 1: Internal schematic diagram* Updated statement ECOPACK®

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